

1a) Discuss Drude model

Classical model of metallic state

- Electrons as independent, classical particles
- Immobile background of metallic ions (continuum)
- Electrons scatter in random directions
- Instantaneous collisions, local thermal equilib.

Use to explain (partly) electrical conductivity, Hall effect, thermal conductivity, thermoelectric effect.

Limitation: Cannot explain low-temp. specific heat, magnetoresistance etc. that require quantum mech.

Sommerfeld theory  $\approx$  Drude model + Fermi-Dirac distrib. and Q.M. descr. of el.

1b) Given: Relaxation time  $\tau$ :

probability  $\frac{dt}{\tau}$  for collision during  $dt$ .

Wanted: Probability of not colliding during time  $t$ .  
 $P(t)$

Solution:

$$P(0) = 1 \quad P(t_1) \cdot P(t_2) = P(t_1 + t_2)$$

$$P(t+dt) = P(t) \cdot P(dt) = P(t) \cdot \left(1 - \frac{dt}{\tau}\right)$$

$$\Rightarrow \frac{P(t+dt) - P(t)}{dt} = - \frac{P(t)}{\tau}$$

$$\frac{dP}{dt} = - \frac{1}{\tau} \cdot P$$

$P(t) = e^{-t/\tau}$

Interpretation:  $\tau$  is the average time between collisions for an electron

2 a) Describe difference between  $E_F$  and  $\mu$

Solution  $\mu$  is appearing in the Fermi-Dirac distribution function:  $f_{FD} = \frac{1}{e^{(E-\mu)/k_B T} + 1}$

At any temperature, the value of  $\mu$  is obtained from

$$\mu: N = \int_0^{\infty} D(E) \cdot f_{FD}(E) dE \quad \text{where } D(E) \text{ is the density of states}$$

and  $N$  is # of free el.

$E_F$  is defined as the highest energy occupied at  $T=0$ .

$$E_F: N = \int_0^{\infty} D(E) \cdot f_{FD}(E, T=0) dE = \int_0^{E_F} D(E) dE$$

i.e.  $\mu(T=0) = E_F$ .

2b) Show  $\mu - E_F \propto T^2$  in free el. model. <sup>⊙ Prefactor containing  $E_F$</sup>

Solution: Free el. model:  $D(E)dE = 2 \cdot \frac{V}{8\pi^3} \cdot 4\pi k^2 dk$

$$N = \int_0^{\infty} D(E) \cdot f(E) dE = \left\{ \text{Sommerfeld expansion} \right\} = \underbrace{\int_0^{\mu} D(E) dE}_{\substack{\downarrow E_F \\ \approx \int_0^{E_F} D(E) dE}} + \frac{\pi^2}{6} (k_B T)^2 \underbrace{D'(\mu)}_{\approx D'(E_F)}$$

$$\Rightarrow D(E_F) \cdot (\mu - E_F) = - \frac{\pi^2}{6} (k_B T)^2 \cdot D'(E_F)$$

$$\left. \begin{array}{l} D(E) dE = A \cdot k^2 dk \\ E = \frac{\hbar^2 k^2}{2m}; \quad k \sim \sqrt{E} \\ dE \sim k dk \end{array} \right\} \Rightarrow \left. \begin{array}{l} D(E) \sim \sqrt{E} \\ D'(E) = \frac{1}{2E} \cdot D(E) \end{array} \right\} \Rightarrow \frac{D'(E_F)}{D(E_F)} = \frac{1}{2E_F}$$

$$\Rightarrow \mu - E_F = - \frac{\pi^2}{6} (k_B T)^2 \cdot \frac{1}{2E_F}$$

2c) Define

Bravais lattice : Infinite, periodic array of points that appears exactly the same from any point

$$\bar{R} = n_1 \bar{a}_1 + n_2 \bar{a}_2 + n_3 \bar{a}_3 \quad n_i = 0, \pm 1, \pm 2, \dots$$

primitive vectors

not all in the same plane

Reciprocal lattice : The reciprocal lattice  $\bar{G}$  of the Bravais lattice  $\bar{R}$  is also a Bravais lattice:

$$\bar{G} = h \bar{b}_1 + k \bar{b}_2 + l \bar{b}_3, \quad h, k, l = 0, \pm 1, \pm 2, \dots$$

$$\text{Where } \bar{a}_i \cdot \bar{b}_j = 2\pi \delta_{ij} = \begin{cases} 2\pi & i=j \\ 0 & i \neq j \end{cases}$$

(this defines  $\bar{b}_j$  and thus  $\bar{G}$ )

3) a) Given: Monoatomic fcc lattice, Miller indices (hkl)

Wanted: Rule for diffraction.

Solution: Structure factor  $S_{\vec{G}} = \sum_{\substack{\text{all} \\ \text{atoms} \\ \text{in cell}}} f_j \cdot e^{i\vec{G} \cdot \vec{r}_j}$

$$\vec{G} = h\vec{b}_1 + k\vec{b}_2 + l\vec{b}_3$$

Describe fcc lattice as cubic lattice + basis of 4 atoms

$\Rightarrow \vec{G}$  cubic lattice with  $\vec{b}_1 = \frac{2\pi}{a} \hat{x}$  etc.

Basis:  $\vec{0}, \left(\frac{1}{2}, \frac{1}{2}, 0\right), \left(\frac{1}{2}, 0, \frac{1}{2}\right), \left(0, \frac{1}{2}, \frac{1}{2}\right)$

expressed in  $(\vec{a}_1, \vec{a}_2, \vec{a}_3)$

$$S_{\vec{G}} = \left\{ \begin{array}{l} \text{all atoms the same} \\ \Rightarrow f_j = f \end{array} \right\} = f \cdot \left( 1 + e^{i\vec{G} \cdot \left(\frac{\vec{a}_1 + \vec{a}_2}{2}\right)} + e^{i\vec{G} \cdot \left(\frac{\vec{a}_1 + \vec{a}_3}{2}\right)} + e^{i\vec{G} \cdot \left(\frac{\vec{a}_2 + \vec{a}_3}{2}\right)} \right)$$

Use  $\vec{a}_i \cdot \vec{b}_j = 2\pi \delta_{ij}$

$$\Rightarrow S_{\vec{G}} = f \left( 1 + e^{i\pi(h+k)} + e^{i\pi(h+l)} + e^{i\pi(k+l)} \right) \neq 0 \quad \text{for diffraction}$$

If all h k l are odd or all are even

$$\Rightarrow S_{\vec{G}} = 4f$$

If one or two of them are odd  $\Rightarrow S_{\vec{G}} = 0$  ( $e^{i\pi} = -1$ )

3b) Given NaCl structure  $\Leftrightarrow$  fcc lattice with basis

$\vec{0}$  and  $\frac{a}{2}(\hat{x} + \hat{y} + \hat{z})$   
Na Cl

Explain: Why same rule as above for NaCl?

Solution: The atomic form factors  $f_j$  are different for Na and Cl  $\Rightarrow$  no general cancellation of further reflexes

3c) Given KCl : NaCl structure but missing reflexes

Explain why missing reflexes, Show All-even reflexes remain

Solution : The atomic form factors for  $K^+$  and  $Cl^-$  are very similar, since they contain the same number of electrons.

We thus have both the condition that all  $hkl$  are odd or even and

a condition that

$$\sum_{\text{two-atom basis}} e^{i\vec{G} \cdot \vec{r}_j} \neq 0$$

$$e^{i\vec{G} \cdot \vec{0}} + e^{i\vec{G} \cdot \left(\frac{\vec{a}_1 + \vec{a}_2 + \vec{a}_3}{2}\right)} = 1 + e^{i\pi(h+k+l)} = \begin{cases} 2 & \text{even sum } h+k+l \\ 0 & \text{odd sum } h+k+l \end{cases}$$

If all  $hkl$  are odd  $\Rightarrow$  odd sum  $\Rightarrow$  no reflex

Thus only all  $hkl$  even remains.

4) Given: Al: fcc with lattice param.  $a = 4.05 \text{ \AA}$

a) Wanted: Expression for the  $k$ -volume of 1st B.Z.

Solution: The Brillouin zone is the Wigner-Seitz cell of the reciprocal lattice, which is a primitive cell, containing one lattice point.

The primitive cell volumes are related by  $V_g = \frac{(2\pi)^3}{V_c}$

Since fcc contains 4 lattice points/cell

$$\Rightarrow V_g = \frac{(2\pi)^3}{\left(\frac{a^3}{4}\right)} = \frac{32\pi^3}{a^3}$$

b) Describe Debye model and find volume of Debye sphere for Al.

Solution: Basic assumptions:

\* Linear relation  $\omega = v_s \cdot |\vec{K}|$   $\vec{K}$ -vector of lattice vibrations  
(sound velocity)

\* Cut-off frequency  $\omega_D$  such that

$$3N = \int_0^{\omega_D} D(\omega) d\omega$$

$\nearrow$  pol. dir. $\uparrow$  # atoms $\searrow$  phonon density of states

$$\text{With } D(\omega) d\omega = 3 \cdot \left(\frac{L}{2\pi}\right)^3 \cdot 4\pi K^2 dK$$

$$\text{and } \frac{N}{L^3} = \frac{N_{\text{cell}}}{V_{\text{cell}}} = \frac{4}{a^3}$$

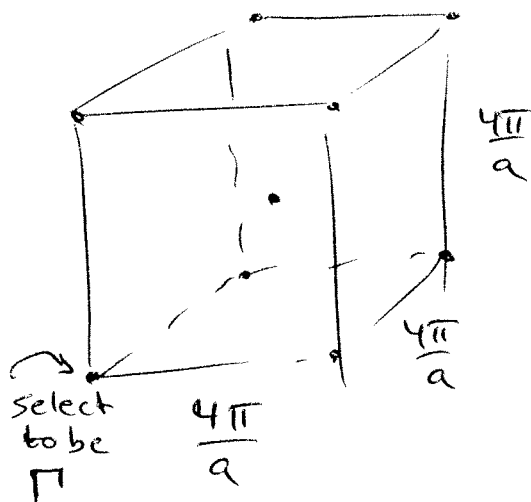
$$\Rightarrow 3 \cdot \left(\frac{4}{a^3}\right) = \int_0^{K_D} 3 \cdot \frac{1}{(2\pi)^3} \cdot 4\pi K^2 dK = \frac{K_D^3}{2\pi^2}$$

$$\Rightarrow K_D^3 = \frac{24\pi^2}{a^3} ; \quad \frac{4}{3}\pi K_D^3 = \frac{32\pi^3}{a^3} = \text{volume of Debye sphere}$$

4c) Compare Debye sphere radius  $\left( \frac{(24\pi^2)^{1/3}}{a} \right)$  from  $b$  with distance from center  $\Gamma$  of B.Z. to  $\left( \frac{3}{\pi} \right)^{1/3} \cdot \frac{2\pi}{a}$  zone boundary in  $[100]$  and  $[111]$  dir. for Al.

Solution: The Brillouin zone is obtained as the Wigner-Seitz cell constructed in the reciprocal lattice.

The reciprocal lattice of fcc is a bcc lattice with lattice param.  $\frac{4\pi}{a}$



The Wigner-Seitz cell is constructed by bisecting nearest-neighbor distances with perpendicular planes.

⊗ In the  $[100]$  direction  $K_{\text{max}}$  will thus be  

$$K_{\text{max}}^{[100]} = \frac{1}{2} \cdot \left( \frac{4\pi}{a} \right) = \frac{2\pi}{a} ; \frac{2\pi}{(24\pi^2)^{1/3}} \approx 1.015 = \left( \frac{\pi}{3} \right)^{1/3}$$
 i.e. Debye sphere a bit smaller than B.Z. in  $[100]$  dir.

⊗ In the  $[111]$  direction:  

$$K_{\text{max}}^{[111]} = \frac{1}{4} \cdot \sqrt{3} \cdot \frac{4\pi}{a} = \frac{\sqrt{3}\pi}{a} ; \frac{\sqrt{3}\pi}{(24\pi^2)^{1/3}} \approx 0.88$$
 i.e.  $K_{\text{max}}^{[111]} < K_D$

5) a) Given : Color of gemstones

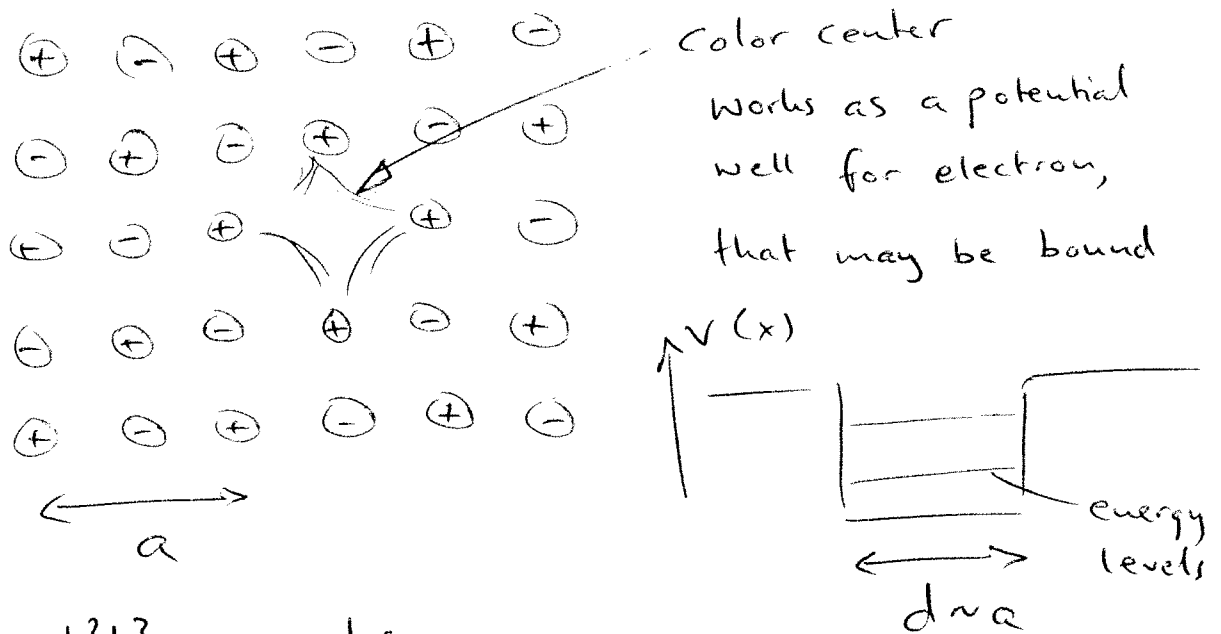
Often due to incomplete 3d shells of metal ions.

Sometimes no metal ions

Wanted : Explanation for colors of crystals and gemstones even without metal ions with 3d orbital

Solution : Such colors arise from color centers, which are created by vacancies in ionic crystals or charged ions in otherwise charge-neutral crystals.

Color can, for instance, arise due to  $\gamma$ -irradiation



$$E = \frac{\hbar^2 k^2}{2m} = h\nu = \frac{hc}{\lambda}$$

$$\Rightarrow \lambda \sim \frac{1}{k^2} = \left\{ k = n \cdot \frac{2\pi}{d} \right\} \sim d^2$$

The localized states arise in the energy gap  
 $\Rightarrow$  optically active in transparent crystal.



5b) Discuss heat conduction in non-metals

x thermal conductivity low, high temp.

x why diffusion-like?

Solution: Heat conduction in non-metals due to phonons.

Thermal conductivity  $K = \frac{1}{3} C_v \lambda v$

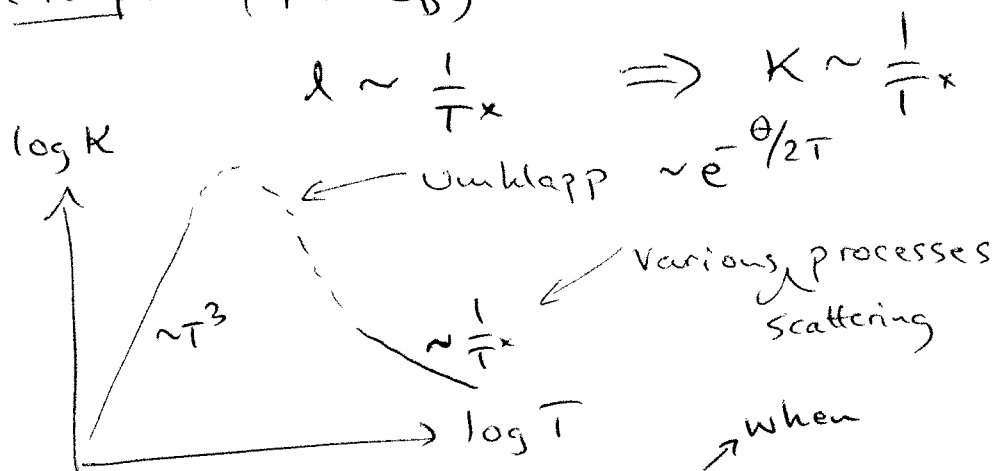
$\swarrow$  heat capacity  
 $\searrow$  phonon mean free path  
 $\swarrow$  phonon velocity  
 $\searrow$  sound velocity  $v_s$

Low temp:  $C_v \sim T^3$  (Debye)

$\lambda$  long, increases with decreasing temp.  
until it reaches sample size  $\rightarrow$  const.

$$\Rightarrow K \sim T^3$$

High temp.:  $(T \gg \Theta_D)$ :  $C_v \sim \text{const.}$



Heat conduction diffusion-like since high-K phonons are involved.  $\Rightarrow$  Umklapp processes  $\Rightarrow$  change of group velocity.

Compare propagation of sound that occur at low-K  $\Leftrightarrow$  n-process where  $\bar{K}_{\text{total}}$  remains unchanged.

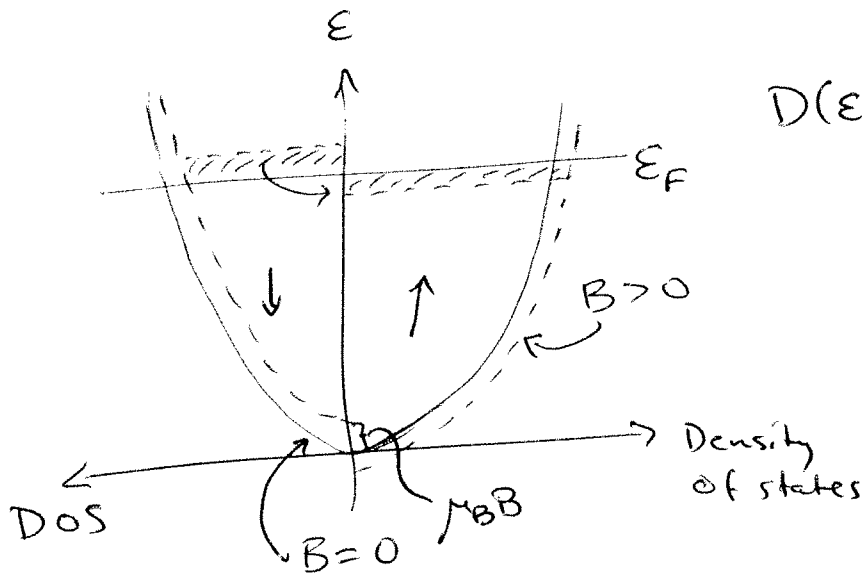
6a) Given: Pauli paramagnetism - itinerant electrons

Wanted: Susceptibility of Pauli paramagnet.

Solution:  $\chi = \frac{\partial M}{\partial H} \approx \frac{M}{H} = \frac{\mu_0 M}{B_a}$

$$M = \mu_B [n(\uparrow) - n(\downarrow)]$$

↙ number of free electrons  
with spin up/down.



$$D(\epsilon) \sim \sqrt{\epsilon}$$

In applied field the electrons with spin along the field will lower their energy.

⇒ some electrons will flip their spin to maintain  $\epsilon_F$ .

$$\begin{aligned} M &= \mu_B (n_{\uparrow} - n_{\downarrow}) = \mu_B \int_{-\infty}^{\infty} \left[ f_{FD}(\epsilon) \cdot \frac{1}{2} D(\epsilon + \mu_B B) - f_{FD}(\epsilon) \cdot \frac{1}{2} D(\epsilon - \mu_B B) \right] d\epsilon = \\ &= \mu_B \int_{-\infty}^{\infty} f_{FD} \cdot \frac{1}{2} \cdot \left\{ \underbrace{D(\epsilon)}_{\text{un}} + \mu_B B \cdot D'(\epsilon) - \left( \underbrace{D(\epsilon)}_{\text{un}} - \mu_B B \cdot D'(\epsilon) \right) \right\} d\epsilon = \\ &= \mu_B^2 B \cdot \int_{-\infty}^{\infty} f_{FD}(\epsilon) D'(\epsilon) d\epsilon = \left\{ \text{partial integration} \right\} = \\ &= \mu_B^2 B \cdot \left[ \underbrace{\int_{-\infty}^{\infty} f(\epsilon) \cdot D(\epsilon) d\epsilon}_{=0} - \int_{-\infty}^{\infty} f'(\epsilon) D(\epsilon) d\epsilon \right] = \\ &= \mu_B^2 B \cdot D(\epsilon_F) \cdot \underbrace{\left( - \int_{-\infty}^{\infty} f'(\epsilon) d\epsilon \right)}_{=+1} = \mu_B^2 B \cdot D(\epsilon_F) \end{aligned}$$

$$\chi = \mu_0 \mu_B^2 D(\epsilon_F)$$

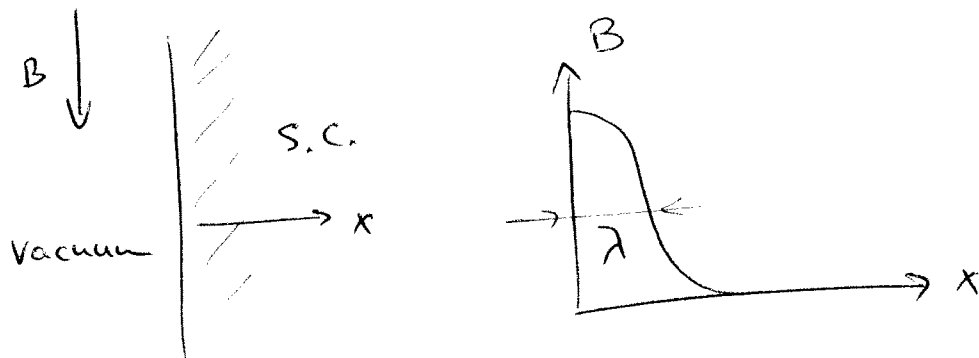
6b) Given : Superconductivity

Two length scales : Coherence length  $\xi$   
Penetration depth  $\lambda$

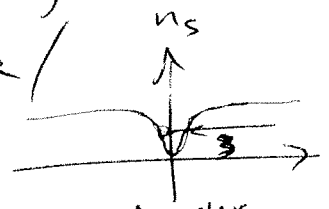
Explain their roles

\* Why response to magnetic fields  
different for  $\lambda < \xi$  and  $\lambda > \xi$  ?

Solution : The penetration depth describes the extent of field & screening currents into the supercond.



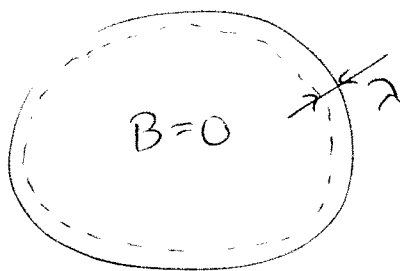
The coherence length describes over which length the superconducting condensate may change / range of interaction.



$\xi \Rightarrow$  size of core of vortex, where supercond. is destroyed

Type - I :

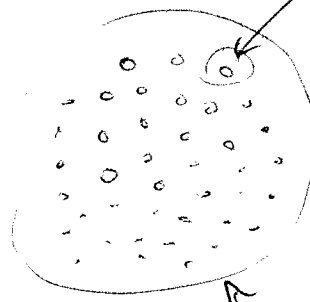
$$\lambda \lesssim \xi$$



Meissner state

Type - II

$$\lambda \gtrsim \xi$$



Vortex  
State  
at high  
fields

around each  
vortex :

magnetic field  
of area

$$\pi \lambda^2$$

core of size

$$\pi \xi^2$$

Field can penetrate  
without completely  
destroying  
superconductivity